

68V N-Channel Trench MOSFET(Preliminary)

General Description

- Trench Power technology
- Low R_{DS(ON)}
- Low Gate Charge
- Optimized for fast-switching applications

Product Summary

$$\begin{split} V_{DS} & 68V \\ I_{D} & (at \ V_{GS} = 10V) \\ R_{DS(ON)} & (at \ V_{GS} = 10V) \\ \end{split} \qquad \qquad \qquad < 5.0 \text{m} \Omega \end{split}$$

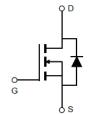
100% UIS Tested



Applications

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial





Part Number	Package Type	Form	Marking
TTD135N68A	TO-252	Tape&Reel	135N68A

Absolute Maximum Ratings (T_A =25°C unless otherwise noted)

Parameter		Symbol	Maximum	Units
Drain-Source Voltage		V _{DS}	68	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Comment	T _C =25°C	I _D	46	۸
Continuous Drain Current	T _C =100°C		46	Α
Pulsed Drain Current ^A		I _{DM}	405	А
Avalanche Current A		I _{AS}	44	А
Single Pulse Avalanche Energy L =0.3mH ^A		E _{AS}	290	mJ
Dawar Dissipation C	T _C =25°C	Б	160	W
Power Dissipation ^C	T _C =100°C	P _D	80	W
Junction and Storage Temperature Range		T _J , T _{STG}	-55 to 175	°C

Thermal Characteristics

Parameter		Symbol	Maximum	Units
Maximum Junction-to-Case	Steady-State	$R_{\Theta JC}$	0.95	°C/W
Maximum Junction-to-Ambient	Steady-State	$R_{\Theta JA}$	100	-C/VV



Electric	cal Characteristics(T _J =25°C ur	nless otherwise	noted)				
Complete	Davamatav	Conditions		Value			11.24
Symbol	Parameter			Min	Тур	Max	Units
STATIC P	ARAMETERS						
BV _{DSS}	Drain-Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$		68			V
		$V_{DC} = 68V$. $V_{CC} = 0V$	T _J =25°C			1	
I _{DSS}	Zero Gate Voltage Drain Current		T _J =100°C			25	μA
I _{GSS}	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$				±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		2	3	4	V
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =10V, I _D =30A			4.2	5	mΩ
g _{FS}	Forward Transconductance	$V_{DS} = 5V, I_{D} = 20A$			30		S
V_{SD}	Diode Forward Voltage	I _S =20A, V _{GS} =0V				1	V
I _S	Maximum Body-Diode Continuous Curre	ent ^B				46	Α
DYNAMIC	PARAMETERS						
C _{iss}	Input Capacitance	$V_{GS} = 0V, V_{DS} = 30V, f = 1MH_Z$			6646		
C _{oss}	Output Capacitance				443		pF
C _{rss}	Reverse Transfer Capacitance				396		
SWITCHI	NG PARAMETERS						
Q _g (10V)	Total Gate Charge	$V_{GS} = 10V, V_{DS} = 30V, I_{D} = 30A$			114		
Q_{gs}	Gate Source Charge				26		nC
Q_{gd}	Gate Drain Charge				34		
t _{D(on)}	Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 30V, I_{D} = 30A,$ $R_{G} = 3\Omega$			17		
t _r	Turn-On Rise Time				11		no
$T_{D(off)}$	Turn-Off Delay Time				55		ns
t _f	Turn-Off Fall Time				15		
t _{rr}	Body Diode Reverse Recovery Time	1 -20A di/d+ -100A/			33		ns
Q _{rr}	Body Diode Reverse Recovery Charge	-I _F =20A, di/dt =100A/μs			51		nC

- A. Single pulse width limited by maximum junction temperature.
- B. The maximum current rating is package limited.
- C. The power dissipation P_D is based on $T_{J(MAX)} = 175$ °C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

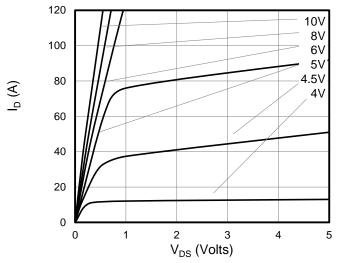
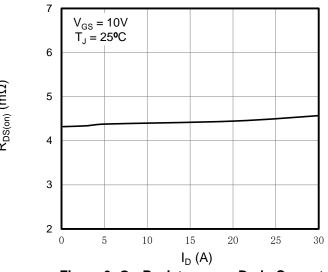


Figure 1: On-Region Characteristics

Figure 2: Transfer Characteristics



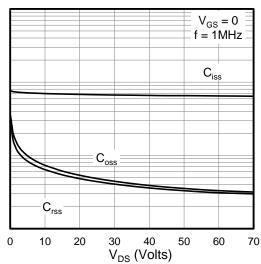
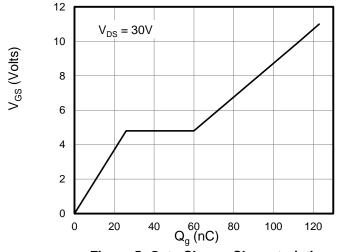


Figure 3: On-Resistance vs. Drain Current

Figure 4: Capacitance Characteristics



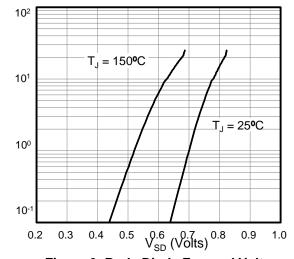


Figure 5: Gate Charge Characteristics

Figure 6: Body Diode Forward Voltage

Capacitance (pF)

I_s (A)

 $Z_{\theta \ JC}$ Normalized Transient Thermal Resistance

Wuxi Unigroup Microelectronics CO.,LTD.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

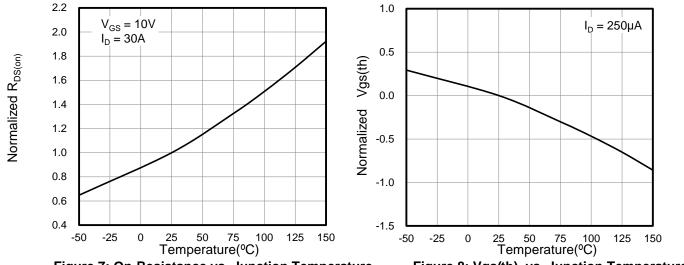
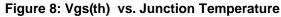


Figure 7: On-Resistance vs. Junction Temperature



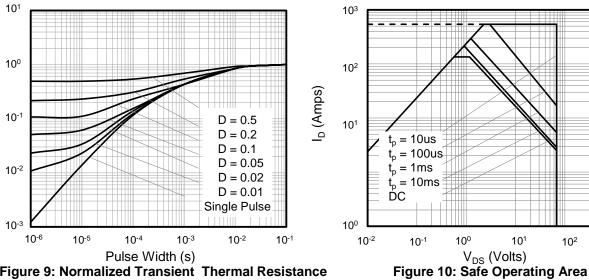


Figure 9: Normalized Transient Thermal Resistance

 10^{3}

 10^{2}



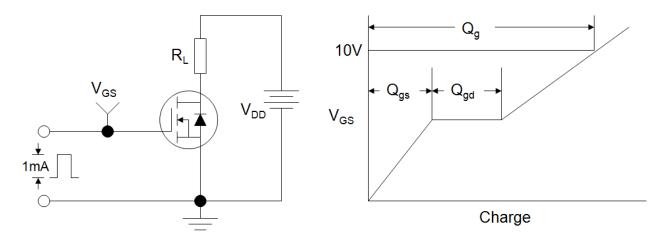


Figure A: Gate Charge Test Circuit and Waveforms

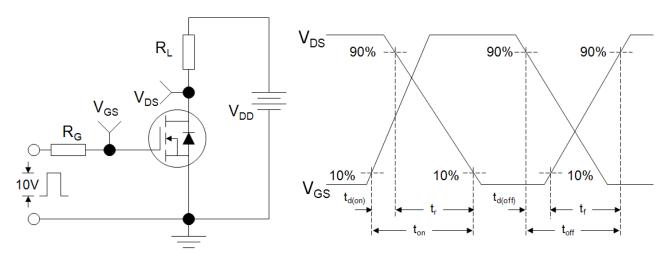


Figure B: Resistive Switching Test Circuit and Waveforms

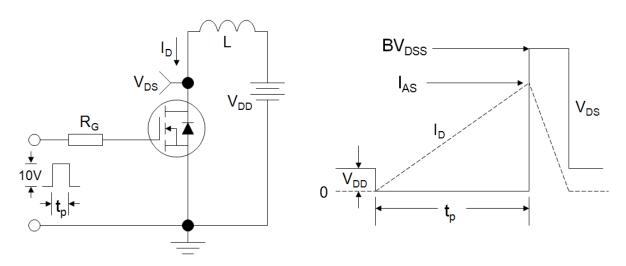
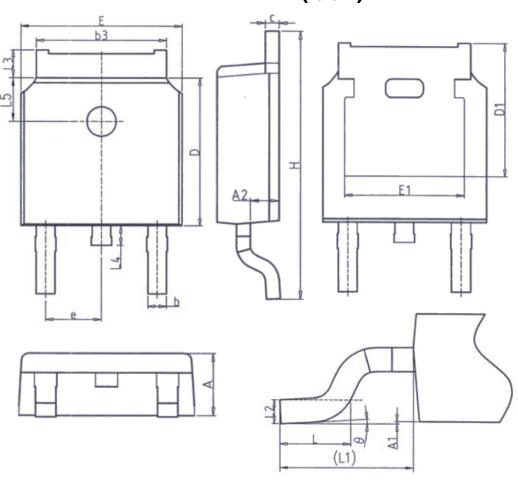


Figure C: Unclamped Inductive Switching (UIS) Test Circuit and Waveforms



TO-252(华天)

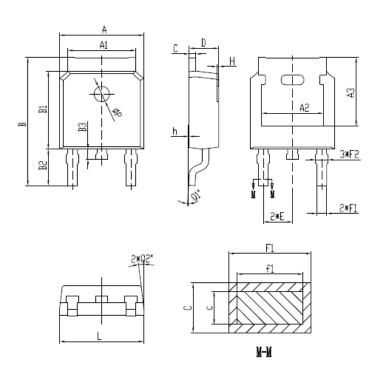


Unit: mm				
Symbol	Symbol Min.			
Α	2. 20	2. 40		
A1	0.00	0. 20		
A2	0. 97	1. 17		
b	0. 68	0. 90		
b3	5. 20	5. 50		
С	0. 43	0. 63		
D	5. 98	6. 22		
D1	1 5. 30REF			
E	6. 40	6. 80		
E1	4. 63	_		

Unit: mm				
Symbol	Min. Max.			
е	2. 286BSC			
Н	9. 40 10. 50			
L	1. 38 1. 75			
L1	2. 90REF			
L2	0. 51BSC			
L3	0.88	1. 28		
L4	- 1.00			
L5	1. 65 1. 95			
θ	0° 8°			



TO-252(海天)



SYMBOL	MIN NOM		MAX
A	6.50	6.60	6. 70
A1	5. 16	5. 31	5. 46
A2		4.83 REF	
A3		5.30 REF	
В	9.77	9.97	10.17
B1	6.00	6. 10	6.20
B2	2.60	2. 80	3.00
B3	0.70	0.80	0.90
С	0.41	_	0.61
С	0.40	0.50	0.60
D	2. 20	2. 30	2. 40
E	2. 186	2. 286	2. 386
F1	0.67	_	0.87
fl	0.66	0.76	0.86
F2	0.76	0.86	0.96
Н	0.00	_	0.30
h	0.00	_	0.20
L	6.50	6.60	6. 70
øP	1.10	1.20	1.30
Q1°	0°	_	8°
Q2°	6°	7°	8°



Disclaimer

All product specifications and data are subject to change without notice.

For documents and material available from this datasheet, Wuxi Unigroup does not warrant or assume any legal liability or responsibility for the accuracy, completeness of any product or technology disclosed hereunder.

No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document or by any conduct of Wuxi Unigroup.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling Wuxi Unigroup products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Wuxi Unigroup for any damages arising or resulting from such use or sale.

Wuxi Unigroup disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Wuxi Unigroup's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

Wuxi Unigroup Microelectronics CO., LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

In the event that any or all Wuxi Unigroup products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

Information (including circuit diagrams and circuit parameters) herein is for example only. It is not guaranteed for volume production. Wuxi Unigroup believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by UNIGROUP manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3